

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

2SA817A

Driver-Stage Amplifier Applications
Voltage Amplifier Applications

Unit: mm

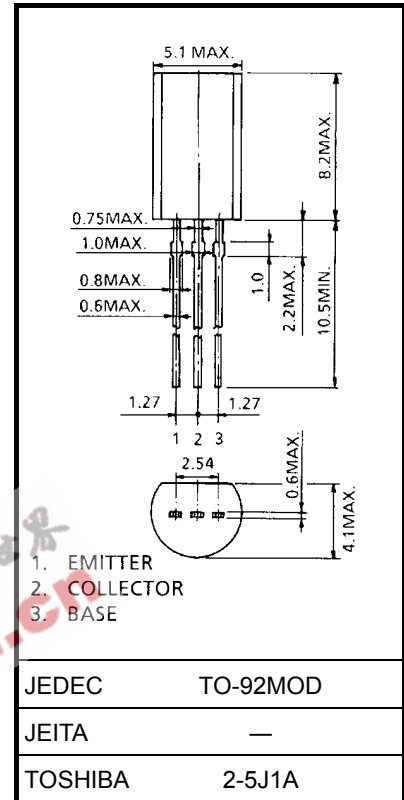
- Complementary to 2SC1627A.
- Driver stage application of 30 to 35 watts amplifiers.

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-80	V
Collector-emitter voltage	V _{CEO}	-80	V
Emitter-base voltage	V _{EB0}	-5	V
Collector current	I _C	-400	mA
Emitter current	I _E	400	mA
Collector power dissipation	P _C	800	mW
Junction temperature	T _j	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



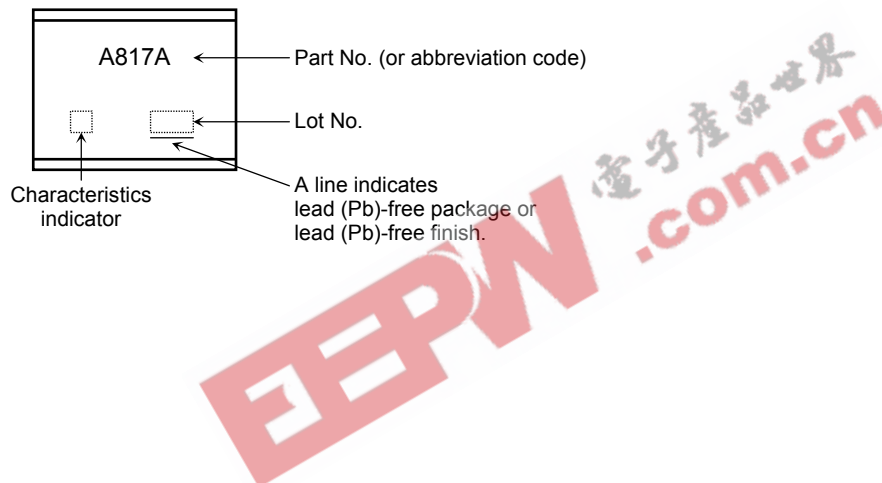
Weight: 0.36 g (typ.)

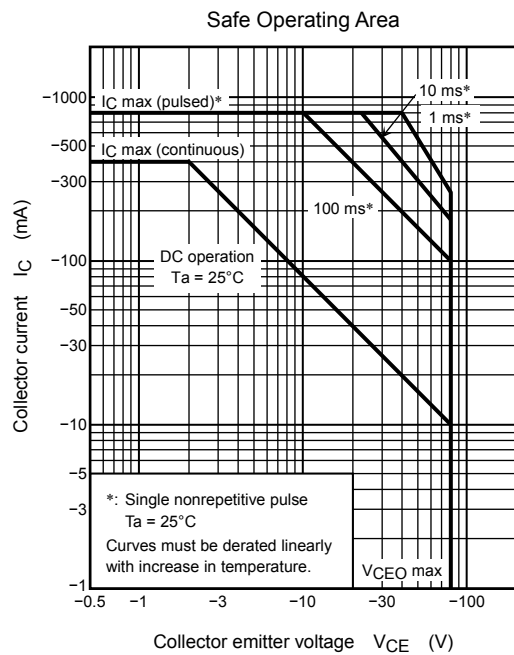
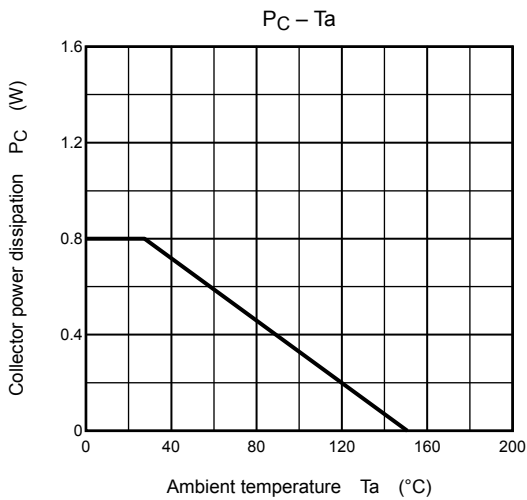
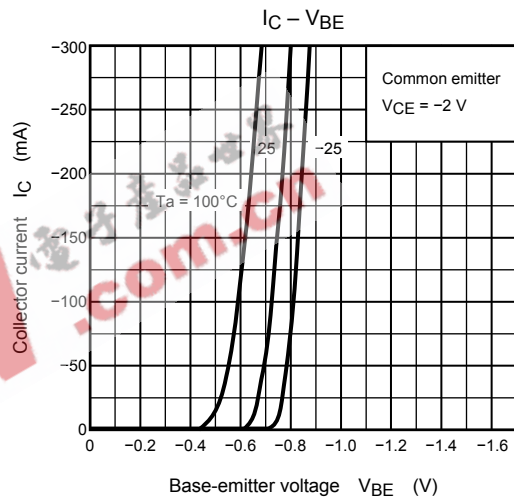
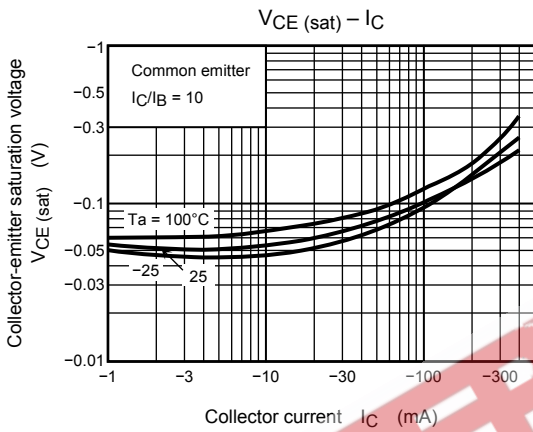
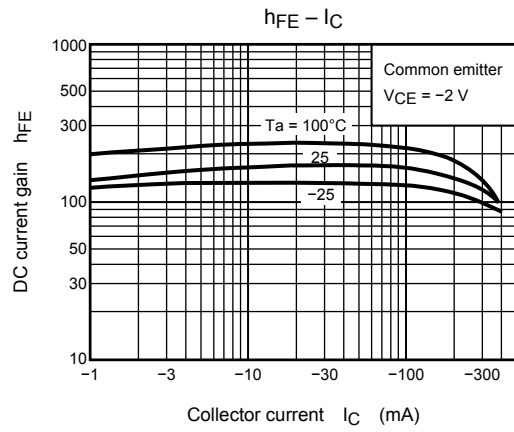
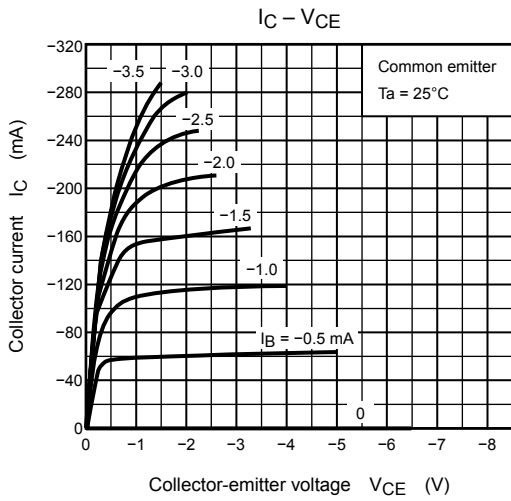
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = -50\text{ V}, I_E = 0$	—	—	-100	nA
Emitter cut-off current	I_{EBO}	$V_{EB} = -5\text{ V}, I_C = 0$	—	—	-100	nA
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -5\text{ mA}, I_B = 0$	-80	—	—	V
DC current gain	$h_{FE(1)}$ (Note)	$V_{CE} = -2\text{ V}, I_C = -50\text{ mA}$	70	—	240	
	$h_{FE(2)}$	$V_{CE} = -2\text{ V}, I_C = -200\text{ mA}$	40	—	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -200\text{ mA}, I_B = -20\text{ mA}$	—	—	-0.4	V
Base-emitter voltage	V_{BE}	$V_{CE} = -2\text{ V}, I_C = -5\text{ mA}$	-0.55	—	-0.8	V
Transition frequency	f_T	$V_{CE} = -10\text{ V}, I_C = -10\text{ mA}$	—	100	—	MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	14	—	pF

Note: $h_{FE(1)}$ classification O: 70 to 140, Y: 120 to 240

Marking





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20070701-EN

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